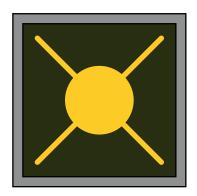


# Vishay Semiconductors

# **Specification of High Power IR Emitting Diode Chip**



### **FEATURES**

Package type: chip

• Package form: single chip

· Technology: surface emitter

 Dimensions chip (L x W x H in mm): 0.260 x 0.260 x 0.17

Peak wavelength: λ = 940 nm

 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN

GREEN (5-2008)

### **DESCRIPTION**

TS9410VB is a high power infrared, 940 nm surface emitting diode in GaAlAs technology with high radiant power and high speed. Polarity configuration is "n-up".

### **GENERAL INFORMATION**

The datasheet is based on Vishay optoelectronics sample testing under certain predetermined and assumed conditions, and is provided for illustration purpose only. Customers are encouraged to perform testing in actual proposed packaged and used conditions. Vishay optoelectronics die products are tested using Vishay optoelectronics based quality assurance procedures and are manufactured using Vishay optoelectronics established processes. Estimates such as those described and set forth in this datasheet for semiconductor die will vary depending on a number of packaging, handling, use, and other factors. Therefore sold die may not perform on an equivalent basis to standard package products.

| PRODUCT SUMMARY |                     |         |                     |                     |
|-----------------|---------------------|---------|---------------------|---------------------|
| COMPONENT       | φ <sub>e</sub> (mW) | φ (deg) | λ <sub>p</sub> (nm) | t <sub>r</sub> (ns) |
| TS9410VB        | 20                  | 60      | 940                 | 10                  |

### Note

· Test condition see table "Basic Characteristics"

| ORDERING INFORMATION |                                     |                  |              |
|----------------------|-------------------------------------|------------------|--------------|
| ORDERING CODE        | PACKAGING                           | REMARKS          | PACKAGE FORM |
| TS9410VB-SD-F        | Wafer sawn on foil with disco frame | MOQ: 385 000 pcs | Chip         |

### Note

MOQ: minimum order quantity

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                                   |                   |             |      |  |
|--|-----------------------------------|-------------------|-------------|------|--|
| PARAMETER  | TEST CONDITION                    | SYMBOL            | VALUE       | UNIT |  |
| Forward current  |                                   | I <sub>F</sub>    | 100         | mA   |  |
| Reverse voltage  |                                   | V <sub>R</sub>    | 10          | V    |  |
| Surge forward current  | $t_p/T = 0.1$ , $t_p = 100 \mu s$ | I <sub>FSM</sub>  | 500         | mA   |  |
| Junction temperature   |                                   | Tj                | 100         | °C   |  |
| Operating temperature range  |                                   | T <sub>amb</sub>  | -40 to +100 | °C   |  |
| Storage temperature range chip   |                                   | T <sub>stg1</sub> | -40 to +110 | °C   |  |
| Storage temperature range on foil  |                                   | T <sub>stg2</sub> | 0 to +40    | °C   |  |

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| <b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                        |                                 |      |      |      |      |
|---|------------------------|---------------------------------|------|------|------|------|
| PARAMETER   | TEST CONDITION         | SYMBOL                          | MIN. | TYP. | MAX. | UNIT |
| Forward voltage   | I <sub>F</sub> = 20 mA | V <sub>F</sub>                  | -    | 1.3  | -    | V    |
|   | I <sub>F</sub> = 50 mA | VF                              | -    | 1.4  | -    |      |
| Radiant power (1)   | I <sub>F</sub> = 20 mA | 4                               | -    | 8    | -    | - mW |
|   | I <sub>F</sub> = 50 mA | φ <sub>e</sub>                  | -    | 20   | -    |      |
| Reverse current   | V <sub>R</sub> = 10 V  | I <sub>R</sub>                  | -    | -    | 1    | μΑ   |
| Angle of half intensity   | I <sub>F</sub> = 50 mA | φ                               | -    | 60   | -    | deg  |
| Peak wavelength   | $I_F = 50 \text{ mA}$  | λρ                              | 925  | 940  | 955  | nm   |
| Spectral bandwidth  | I <sub>F</sub> = 50 mA | λ <sub>0.5</sub>                | -    | 50   | -    | nm   |
| Rise time / fall time   | I <sub>F</sub> = 50 mA | t <sub>r</sub> , t <sub>f</sub> | -    | 10   | -    | ns   |

#### Note

### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

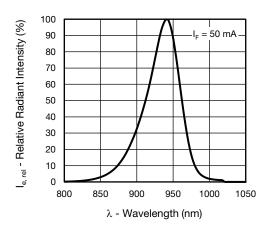


Fig. 1 - Relative Spectral Emission  $\phi_{e \text{ rel}} = f(\lambda)$ 

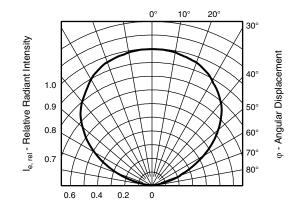


Fig. 2 - Radiant Characteristics  $I_{rel} = f(\phi)$ 

### **DIMENSIONS**

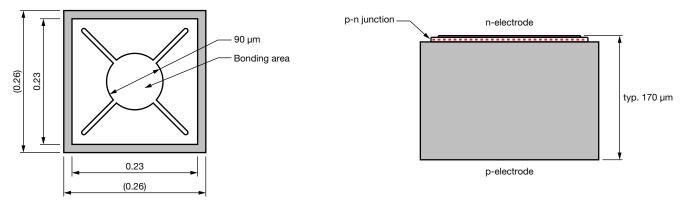


Fig. 3 - Sectional View

<sup>(1)</sup> The measurements are based on samples of die which are mounted on a TO-18 gold header without resin coating



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| MECHANICAL DIMENSIONS             |                |      |      |      |      |
|-----------------------------------|----------------|------|------|------|------|
| PARAMETER                         | SYMBOL         | MIN. | TYP. | MAX. | UNIT |
| Length of chip edge (x-direction) | L <sub>x</sub> | -    | 0.26 | -    | mm   |
| Length of chip edge (y-direction) | L <sub>y</sub> | -    | 0.26 | -    | mm   |
| Die height                        | Н              | -    | 0.17 | -    | mm   |
| Diameter of bondpad               | d              | 0.08 | 0.09 | 0.10 | mm   |

| ADDITIONAL INFORMATION           |               |  |  |  |
|----------------------------------|---------------|--|--|--|
| Frontside metallization, cathode | Gold alloy    |  |  |  |
| Backside metallization, anode    | Gold alloy    |  |  |  |
| Dicing                           | Sawing        |  |  |  |
| Die bonding technology           | Epoxy bonding |  |  |  |

#### Note

All chips are checked in accordance with the Vishay Semiconductor, specification of visual inspection FVOV6870.
 The visual inspection shall be made in accordance with the "specification of visual inspection as referenced". The visual inspection of chip backside is performed with stereo microscope with incident light and 40x to 80x magnification.
 The quality inspection (final visual inspection) is performed by production. An additional visual inspection step as special release procedure by QM is not installed

### HANDLING AND STORAGE CONDITIONS

- The hermetically sealed shipment lots shall be opened in temperature and moisture controlled cleanroom environment only. It is mandatory to follow the rules for disposition of material that can be hazardous for humans and environment
- Product must be handled only at ESD safe workstations. Standard ESD precautions and safe work environments are as defined in MIL-HDBK-263
- Singulated die are not to be handled with tweezers. A vacuum wand with non metallic ESD protected tip should be used

### **PACKING**

Chips are fixed on adhesive foil. Upon request the foils can be mounted on plastic frame or disco frame. For shipment, the wafers are arranged to stacks and hermetically sealed in plastic bags to ensure protection against environmental influence (humidity and contamination).

Use for recycling reliable operators only. We can help getting in touch with your nearest sales office. By agreement we will take back packing material, if it is sorted. You will have to bear the costs of transport. We will invoice you for any costs incurred for packing material that is returned unsorted or which we are not obliged to accept.



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